SAMYANG ELECTRONICS

SB0620 --- SB06A0

SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 20 --- 200 V
CURRENT: 0.6A

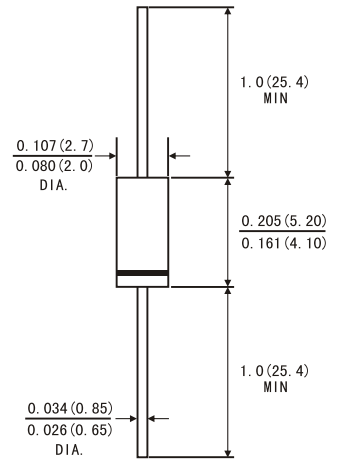
FEATURES

- ◇Metal-semiconductor junction with guard ring
- ◇Epitaxial construction
- ◇Low forward voltage drop,low switching losses
- ◇High surge capability
- ◇For use in low voltage,high frequency inverters free wheeling,and polarity protection applications
- ◇The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇Case:JEDEC DO--41,molded plastic
- ◇Terminals: Axial lead ,solderable per MIL- STD-750,Method 2026
- ◇Polarity: Color band denotes cathode
- ◇Weight: 0.012ounces,0.33 grams
- ◇Mounting position: Any

DO - 41



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

	Symbols	SB 0620	SB 0630	SB 0640	SB 0650	SB 0660	SB 0680	SB 06A0	Units
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	Volts
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	57	71	Volts
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length(see Fig. 1)	$I_{(AV)}$	0.6							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	20.0							Amps
Maximum instantaneous forward voltage at 0. 6 A(Note 1)	V_F	0.55			0.70		0.85		Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1) T_A=25°C	I_R	0.2							mA
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1) T_A=100°C	I_R	10							mA
Typical junction capacitance(Note 3)	C_J	110							PF
Typical thermal resistance(Note 2)	$R_{\theta JA}$ $R_{\theta JL}$	50.0 15.0							℃/W
Operating junction temperature range	T_J	-65 to+150							℃
Storage temperature range	T_{STG}	-65 to+150							℃

NOTE: 1. Pulse test:300us pulse width,1% duty cycle.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3.Thermal resistance junction to ambient

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FIG.1-FORWARD CURRENT DERATING CURVE

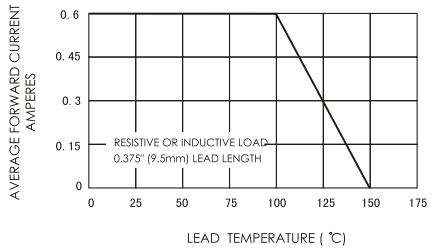


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

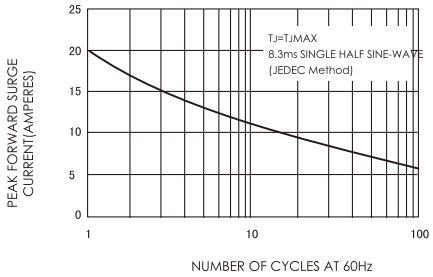


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

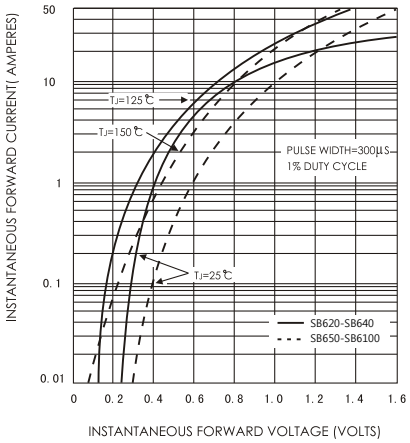


FIG.4-TYPICAL REVERSE CHARACTERISTICS

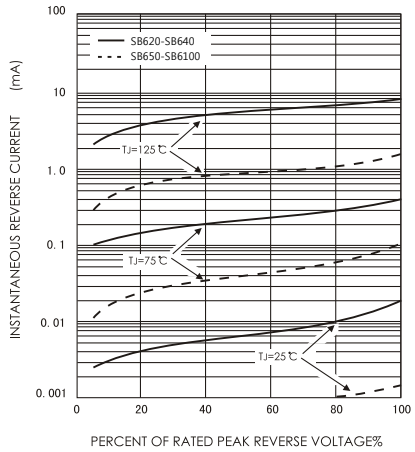


FIG.5-TYPICAL JUNCTION CAPACITANCE

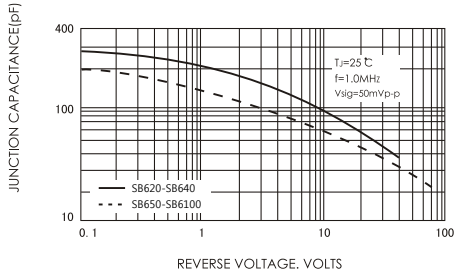


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

